

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L4	173	(oxide: near5 apart: near5 surface)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 00:24
L5	92	((oxide adj (film or layer)) near5 apart near5 surface)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 00:28
L6	4	((buried adj oxide adj (film or layer)) near5 apart near5 surface)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 00:29
L7	238	((buried adj oxide adj (film or layer)) with (epitaxy or epitaxial or epitaxially))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 00:29
L8	52	((buried adj oxide adj (film or layer)) with semiconductor with substrate with (epitaxy or epitaxial or epitaxially))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 00:30
L9	44	((buried adj oxide adj (film or layer)) near10 semiconductor with substrate with (epitaxy or epitaxial or epitaxially))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 00:30
L10	40	((buried adj oxide adj (film or layer)) near10 semiconductor near10 substrate with (epitaxy or epitaxial or epitaxially))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 00:30
L11	32	((buried adj oxide adj (film or layer)) near10 semiconductor near10 substrate near10 (epitaxy or epitaxial or epitaxially))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/19 00:36